## **SIEMENS**

Data sheet 3RF2150-1AA45



Semiconductor relay, 1-phase 3RF2 Overall width 22.5 mm, 50 A 48-600 V / 4-30 V DC screw terminal Blocking voltage 1200 V

product brand name	SIRIUS
product designation	solid-state relay
design of the product	single-phase
product type designation	3RF21
manufacturer's article number	
<ul><li>_1 of the accessories that can be ordered</li></ul>	3RF2900-3PA88
<ul><li>_2 of the accessories that can be ordered</li></ul>	3RF2950-0HA16
<ul> <li>_3 of the accessories that can be ordered</li> </ul>	3RF2900-0EA18
4 of the accessories that can be ordered	3RF2950-0GA16
<ul><li>_5 of the accessories that can be ordered</li></ul>	3RF2920-0FA08
product designation	
<ul><li>_1 of the accessories that can be ordered</li></ul>	terminal cover
<ul><li>_2 of the accessories that can be ordered</li></ul>	power regulator
<ul><li>_3 of the accessories that can be ordered</li></ul>	converter
<ul><li>_4 of the accessories that can be ordered</li></ul>	load monitoring
<ul><li>_5 of the accessories that can be ordered</li></ul>	load monitoring, basis
General technical data	
product function	zero-point switching
power loss [V·A] maximum	66 VA
power loss [W] for rated value of the current	
<ul> <li>at AC in hot operating state</li> </ul>	66 W
<ul> <li>at AC in hot operating state per pole</li> </ul>	66 W
without load current share typical	0.5 W
insulation voltage rated value	600 V
type of voltage	
<ul> <li>of the operating voltage</li> </ul>	AC
of the control supply voltage	DC
surge voltage resistance of main circuit rated value	6 kV
shock resistance according to IEC 60068-2-27	15g / 11 ms
vibration resistance according to IEC 60068-2-6	2g
reference code according to DIN 40719 extended according to IEC 204-2 according to IEC 750	K
reference code according to EN 61346-2	Q
reference code according to IEC 81346-2	Q
Substance Prohibitance (Date)	05/28/2009
SVHC substance name	Lead - 7439-92-1 Lead monoxide (lead oxide) - 1317-36-8
Main circuit	
number of poles for main current circuit	1
number of NO contacts for main contacts	1
number of NC contacts for main contacts	0

tune of voltage of the operating voltage	AC
type of voltage of the operating voltage operating voltage	AC .
• at AC	
	48 600 V
— at 50 Hz rated value	48 600 V
— at 60 Hz rated value	
operating frequency rated value	50 60 Hz
relative symmetrical tolerance of the operating frequency	10 %
operating range relative to the operating voltage at AC	40 000 V
• at 50 Hz	40 660 V
• at 60 Hz	40 660 V
operational current	50 A
at AC-51 rated value	50 A
according to UL 508 rated value	50 A
ampacity maximum	50 A
operational current minimum	500 mA
rate of voltage rise at the thyristor for main contacts maximum permissible	1 000 V/μs
blocking voltage at the thyristor for main contacts maximum permissible	1 200 V
reverse current of the thyristor	10 mA
derating temperature	40 °C
surge current resistance rated value	600 A
I2t value maximum	1 800 A²·s
Control circuit/ Control	
type of voltage of the control supply voltage	DC
control supply voltage 1 at DC	
<ul> <li>rated value maximum permissible</li> </ul>	30 V
•	4 30 V
control supply voltage	
<ul> <li>at DC initial value for signal &lt;1&gt; detection</li> </ul>	4 V
at DC full-scale value for signal<0> recognition	1 V
control current at minimum control supply voltage	
• at DC	13 mA
control current at DC rated value	15 mA
ON-delay time	1 ms; additionally max. one half-wave
OFF-delay time	1 ms; additionally max. one half-wave
Auxiliary circuit	
number of NC contacts for auxiliary contacts	0
number of NO contacts for auxiliary contacts	0
number of CO contacts for auxiliary contacts	0
Installation/ mounting/ dimensions	
fastening method side-by-side mounting	Yes
fastening method	screw fixing
design of the thread of the screw for securing the equipment	M4
tightening torque of fixing screw maximum	1.5 N·m
tightening torque [lbf·in] of fixing screw maximum	13 lbf·in
height	85 mm
width	22.5 mm
depth	48 mm
Connections/ Terminals	
product component removable terminal for auxiliary and control circuit	Yes
type of electrical connection	
• for main current circuit	screw-type terminals
for auxiliary and control circuit	screw-type terminals
type of connectable conductor cross-sections	
• for main contacts	
— solid	2x (1.5 2.5 mm²), 2x (2.5 6 mm²)
<ul> <li>finely stranded with core end processing</li> </ul>	2x (1 2.5 mm²), 2x (2.5 6 mm²), 1x 10 mm²
<ul> <li>for AWG cables for main contacts</li> </ul>	2x (14 10)
connectable conductor cross-section for main contacts	

a colid or atrandad	1.5 6 mm²
solid or stranded     finally stranded with core and processing.	1.5 6 mm <sup>2</sup>
• finely stranded with core end processing  type of connectable conductor cross-sections	1 10 mm²
for auxiliary and control contacts  — solid	1v (0.5 2.5 mm²) 2v (0.5 1.0 mm²)
— finely stranded with core end processing	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
— finely stranded with core end processing     — finely stranded without core end processing	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²) 1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
for AWG cables for auxiliary and control contacts	1x (AWG 20 12)
AWG number as coded connectable conductor cross section for	14 10
main contacts	17 10
tightening torque	
<ul> <li>for main contacts with screw-type terminals</li> </ul>	2 2.5 N·m
<ul> <li>for auxiliary and control contacts with screw-type terminals</li> </ul>	0.5 0.6 N·m
tightening torque [lbf·in]	
<ul> <li>for main contacts with screw-type terminals</li> </ul>	7 10.3 lbf·in
<ul> <li>for auxiliary and control contacts with screw-type terminals</li> </ul>	4.5 5.3 lbf·in
design of the thread of the connection screw	
• for main contacts	M4
of the auxiliary and control contacts	M3
stripped length of the cable	
• for main contacts	7 mm
for auxiliary and control contacts	7 mm
Electrical Safety	
protection class IP on the front according to IEC 60529	IP20
touch protection on the front according to IEC 60529	finger-safe, for vertical contact from the front
Ambient conditions	1000
installation altitude at height above sea level maximum	1 000 m
ambient temperature	05
during operation	-25 +60 °C
during storage	-55 +80 °C
Flootromagnatic compatibility	
Electromagnetic compatibility	
conducted interference	2 kV / 5 kHz hehavior criterion 2
conducted interference • due to burst according to IEC 61000-4-4	2 kV / 5 kHz behavior criterion 2
conducted interference  • due to burst according to IEC 61000-4-4  • due to conductor-earth surge according to IEC 61000-4-5	2 kV behavior criterion 2
conducted interference • due to burst according to IEC 61000-4-4	
conducted interference  • due to burst according to IEC 61000-4-4  • due to conductor-earth surge according to IEC 61000-4-5  • due to conductor-conductor surge according to IEC	2 kV behavior criterion 2
conducted interference  • due to burst according to IEC 61000-4-4  • due to conductor-earth surge according to IEC 61000-4-5  • due to conductor-conductor surge according to IEC 61000-4-5  • due to high-frequency radiation according to IEC 61000-	2 kV behavior criterion 2 1 kV behavior criterion 2
conducted interference  • due to burst according to IEC 61000-4-4  • due to conductor-earth surge according to IEC 61000-4-5  • due to conductor-conductor surge according to IEC 61000-4-5  • due to high-frequency radiation according to IEC 61000-4-6	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1
conducted interference  • due to burst according to IEC 61000-4-4  • due to conductor-earth surge according to IEC 61000-4-5  • due to conductor-conductor surge according to IEC 61000-4-5  • due to high-frequency radiation according to IEC 61000-4-6  field-based interference according to IEC 61000-4-3  electrostatic discharge according to IEC 61000-4-2  conducted HF interference emissions according to	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1
conducted interference  • due to burst according to IEC 61000-4-4  • due to conductor-earth surge according to IEC 61000-4-5  • due to conductor-conductor surge according to IEC 61000-4-5  • due to high-frequency radiation according to IEC 61000-4-6  field-based interference according to IEC 61000-4-3  electrostatic discharge according to IEC 61000-4-2  conducted HF interference emissions according to CISPR11	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
conducted interference  • due to burst according to IEC 61000-4-4  • due to conductor-earth surge according to IEC 61000-4-5  • due to conductor-conductor surge according to IEC 61000-4-5  • due to high-frequency radiation according to IEC 61000-4-6  field-based interference according to IEC 61000-4-3  electrostatic discharge according to IEC 61000-4-2  conducted HF interference emissions according to CISPR11  field-bound HF interference emission according to CISPR11	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2
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conducted interference  • due to burst according to IEC 61000-4-4  • due to conductor-earth surge according to IEC 61000-4-5  • due to conductor-conductor surge according to IEC 61000-4-5  • due to high-frequency radiation according to IEC 61000-4-6  field-based interference according to IEC 61000-4-3  electrostatic discharge according to IEC 61000-4-2  conducted HF interference emissions according to CISPR11  field-bound HF interference emission according to CISPR11  Short-circuit protection, design of the fuse link  manufacturer's article number  • of gS fuse for semiconductor protection at NH design usable  • of full range R fuse link for semiconductor protection at cylindrical design usable  • of back-up R fuse link for semiconductor protection at NH	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments  3NE1802-0; These fuses have a smaller rated current than the semiconductor relays
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conducted interference  • due to burst according to IEC 61000-4-4  • due to conductor-earth surge according to IEC 61000-4-5  • due to conductor-conductor surge according to IEC 61000-4-5  • due to high-frequency radiation according to IEC 61000-4-6  field-based interference according to IEC 61000-4-3  electrostatic discharge according to IEC 61000-4-2  conducted HF interference emissions according to CISPR11  field-bound HF interference emission according to CISPR11  Short-circuit protection, design of the fuse link  manufacturer's article number  • of gS fuse for semiconductor protection at NH design usable  • of full range R fuse link for semiconductor protection at cylindrical design usable  • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable  • of back-up R fuse link for semiconductor protection at cylindrical design 12 x 58 mm usable	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments  3NE1802-0: These fuses have a smaller rated current than the semiconductor relays 5SE1335: These fuses have a smaller rated current than the semiconductor relays 3NE8017-1 3NC1450
conducted interference  • due to burst according to IEC 61000-4-4  • due to conductor-earth surge according to IEC 61000-4-5  • due to conductor-conductor surge according to IEC 61000-4-5  • due to high-frequency radiation according to IEC 61000-4-6  field-based interference according to IEC 61000-4-3  electrostatic discharge according to IEC 61000-4-2  conducted HF interference emissions according to CISPR11  field-bound HF interference emission according to CISPR11  Short-circuit protection, design of the fuse link  manufacturer's article number  • of gS fuse for semiconductor protection at NH design usable  • of full range R fuse link for semiconductor protection at cylindrical design usable  • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable  • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable  • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable  • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable	2 kV behavior criterion 2  1 kV behavior criterion 2  140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1  80 MHz 1 GHz 10 V/m, behavior criterion 1  4 kV contact discharging / 8 kV air discharging, behavior criterion 2  Class A for industrial environment  Class B for the domestic, business and commercial environments  3NE1802-0: These fuses have a smaller rated current than the semiconductor relays  5SE1335: These fuses have a smaller rated current than the semiconductor relays  3NC1450  3NC2250
conducted interference  • due to burst according to IEC 61000-4-4  • due to conductor-earth surge according to IEC 61000-4-5  • due to conductor-conductor surge according to IEC 61000-4-5  • due to high-frequency radiation according to IEC 61000-4-6  field-based interference according to IEC 61000-4-3  electrostatic discharge according to IEC 61000-4-2  conducted HF interference emissions according to CISPR11  field-bound HF interference emission according to CISPR11  Short-circuit protection, design of the fuse link  manufacturer's article number  • of gS fuse for semiconductor protection at NH design usable  • of full range R fuse link for semiconductor protection at cylindrical design usable  • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable  • of back-up R fuse link for semiconductor protection at cylindrical design 22 x 58 mm usable  manufacturer's article number of the gG fuse	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments  3NE1802-0; These fuses have a smaller rated current than the semiconductor relays 5SE1335; These fuses have a smaller rated current than the semiconductor relays 3NE8017-1 3NC1450 3NC2250
conducted interference  • due to burst according to IEC 61000-4-4  • due to conductor-earth surge according to IEC 61000-4-5  • due to conductor-conductor surge according to IEC 61000-4-5  • due to high-frequency radiation according to IEC 61000-4-6  field-based interference according to IEC 61000-4-3  electrostatic discharge according to IEC 61000-4-2  conducted HF interference emissions according to CISPR11  field-bound HF interference emission according to CISPR11  Short-circuit protection, design of the fuse link  manufacturer's article number  • of gS fuse for semiconductor protection at NH design usable  • of full range R fuse link for semiconductor protection at cylindrical design usable  • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable  • of back-up R fuse link for semiconductor protection at cylindrical design 22 x 58 mm usable  manufacturer's article number of the gG fuse  • at NH design usable	2 kV behavior criterion 2  1 kV behavior criterion 2  140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1  80 MHz 1 GHz 10 V/m, behavior criterion 1  4 kV contact discharging / 8 kV air discharging, behavior criterion 2  Class A for industrial environment  Class B for the domestic, business and commercial environments  3NE1802-0: These fuses have a smaller rated current than the semiconductor relays  5SE1335; These fuses have a smaller rated current than the semiconductor relays  3NE8017-1  3NC1450  3NA6807; These fuses have a smaller rated current than the semiconductor relays  3NBC2250
conducted interference  • due to burst according to IEC 61000-4-4  • due to conductor-earth surge according to IEC 61000-4-5  • due to conductor-conductor surge according to IEC 61000-4-5  • due to high-frequency radiation according to IEC 61000-4-6  field-based interference according to IEC 61000-4-3  electrostatic discharge according to IEC 61000-4-2  conducted HF interference emissions according to CISPR11  field-bound HF interference emission according to CISPR11  Short-circuit protection, design of the fuse link  manufacturer's article number  • of gS fuse for semiconductor protection at NH design usable  • of full range R fuse link for semiconductor protection at cylindrical design usable  • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable  • of back-up R fuse link for semiconductor protection at cylindrical design 22 x 58 mm usable  manufacturer's article number of the gG fuse  • at NH design usable  • at cylindrical design 22 x 58 mm usable	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment  Class B for the domestic, business and commercial environments  3NE1802-0: These fuses have a smaller rated current than the semiconductor relays 5SE1335: These fuses have a smaller rated current than the semiconductor relays 3NE8017-1 3NC1450 3NC2250  3NA6807: These fuses have a smaller rated current than the semiconductor relays 3NW6205-1: These fuses have a smaller rated current than the semiconductor relays

Approvals Certificates

General Product Approval

Confirmation











EMV

Test Certificates other Railway Environment

Special Test Certificate

Type Test Certificates/Test Report

Confirmation



Special Test Certificate

Environmental Confirmations

## Further information

Information on the packaging

https://support.industry.siemens.com/cs/ww/en/view/109813875

Information- and Downloadcenter (Catalogs, Brochures,...)

https://www.siemens.com/ic10

Industry Mall (Online ordering system)

https://mall.industry.siemens.com/mall/en/en/Catalog/product?mlfb=3RF2150-1AA45

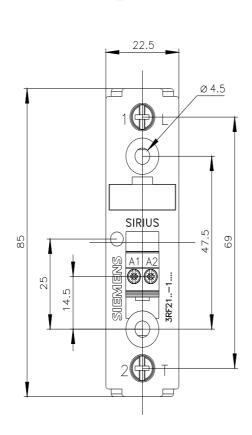
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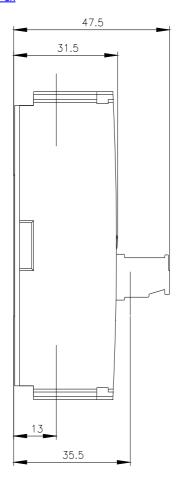
http://support.automation.siemens.com/WW/CAXorder/default.aspx?lang=en&mlfb=3RF2150-1AA45

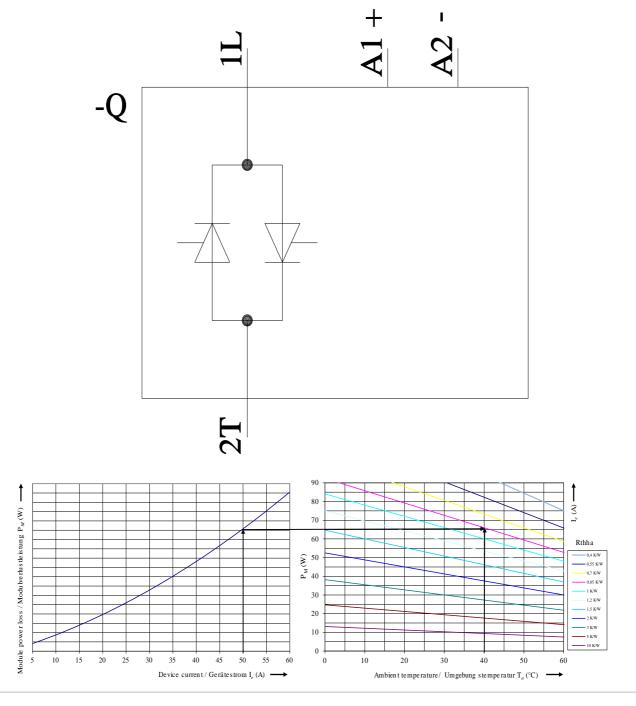
Service&Support (Manuals, Certificates, Characteristics, FAQs,...)

https://support.industry.siemens.com/cs/ww/en/ps/3RF2150-1AA45

Image database (product images, 2D dimension drawings, 3D models, device circuit diagrams, EPLAN macros, ...) <a href="http://www.automation.siemens.com/bilddb/cax\_de.aspx?mlfb=3RF2150-1AA45&lang=en">http://www.automation.siemens.com/bilddb/cax\_de.aspx?mlfb=3RF2150-1AA45&lang=en</a>







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